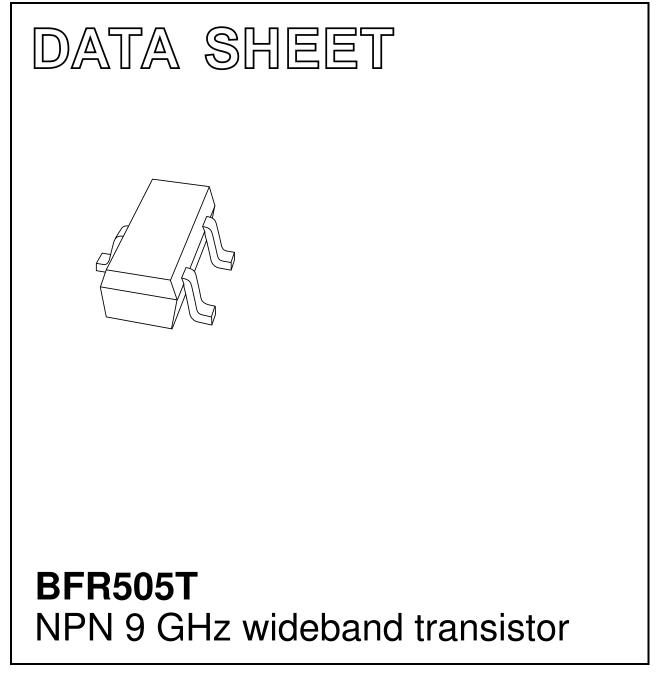
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 2000 Mar 14 2000 May 17



FEATURES

- Low current consumption
- High power gain
- Low noise figure
- High transition frequency
- Gold metallization ensures
 excellent reliability
- SOT416 (SC-75) package.

APPLICATIONS

Low power amplifiers, oscillators and mixers particularly in RF portable communication equipment (cellular phones, cordless phones and pagers) up to 2 GHz.

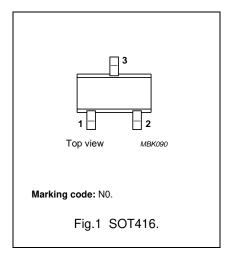
QUICK REFERENCE DATA

DESCRIPTION

NPN transistor in a plastic SOT416 (SC-75) package.

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	-	20	V
V _{CES}	collector-emitter voltage	$R_{BE} = 0$	-	-	15	V
I _C	DC collector current		-	-	18	mA
P _{tot}	total power dissipation	$T_s \le 75 \text{ °C}; \text{ note } 1$	-	-	150	mW
h _{FE}	DC current gain	$I_{C} = 5 \text{ mA}; V_{CE} = 6 \text{ V}; T_{j} = 25 \text{ °C}$	60	120	250	
f _T	transition frequency	$I_{C} = 5 \text{ mA}; V_{CE} = 6 \text{ V}; f = 1 \text{ GHz};$ $T_{amb} = 25 ^{\circ}\text{C}$	-	9	-	GHz
G _{UM}	maximum unilateral power gain	$I_{C} = 5 \text{ mA}; V_{CE} = 6 \text{ V}; f = 900 \text{ MHz}; T_{amb} = 25 \text{ °C}$	-	17	-	dB
F	noise figure	I _C = 1.25 mA; V _{CE} = 6 V; f = 900 MHz; T _{amb} = 25 °C	-	1.2	1.7	dB

LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	20	V
V _{CE}	collector-emitter voltage	$R_{BE} = 0$	-	15	V
V _{EBO}	emitter-base voltage	open collector	-	2.5	V
I _C	DC collector current		-	18	mA
P _{tot}	total power dissipation	$T_s \le 75 \text{ °C};$ note 1	-	150	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C

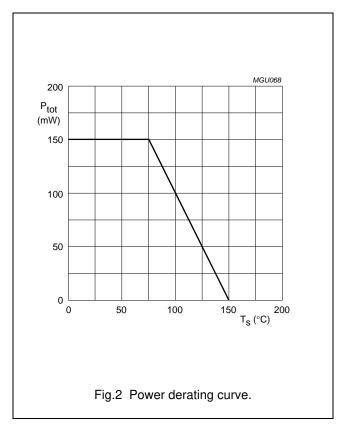
Note

1. T_s is the temperature at the soldering point of the collector pin.

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THERMAL RESISTANCE

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Rth j-s thermal resistance from junction to soldering point 500 K/W	R _{th j-s}	thermal resistance from junction to soldering point	500	K/W



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CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$; unless otherwise specified.

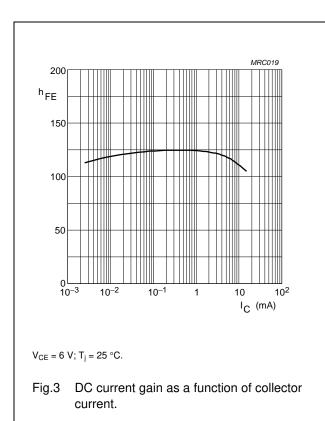
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	$I_{E} = 0; V_{CB} = 6 V$	_	_	50	nA
h _{FE}	DC current gain	$I_{C} = 5 \text{ mA}; V_{CE} = 6 \text{ V}$	60	120	250	
C _c	collector capacitance	$I_E = i_e = 0; V_{CB} = 6 V; f = 1 MHz$	-	0.4	-	pF
C _e	emitter capacitance	$I_{C} = i_{c} = 0; V_{EB} = 0.5 V; f = 1 MHz$	-	0.4	-	pF
C _{re}	feedback capacitance	$I_{C} = 0; V_{CB} = 6 V; f = 1 MHz$	_	0.3	_	pF
f _T	transition frequency	$I_{C} = 5 \text{ mA}; V_{CE} = 6 \text{ V}; f = 1 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$	-	9	-	GHz
G _{UM}	maximum unilateral power gain; note 1	$I_{C} = 5 \text{ mA}; V_{CE} = 6 \text{ V}; T_{amb} = 25 \text{ °C};$ f = 900 MHz f = 2 GHz		17 10		dB dB
S ₂₁ ²	insertion power gain	$I_C = 5 \text{ mA}; V_{CE} = 6 \text{ V}; \text{ f} = 900 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$	13	14	-	dB
F	noise figure	$\label{eq:Gamma-star} \begin{array}{l} \Gamma_{s}=\Gamma_{opt}; \ I_{C}=1.25 \ \text{mA}; \ V_{CE}=6 \ \text{V}; \\ f=900 \ \text{MHz}; \ T_{amb}=25 \ ^{\circ}\text{C} \end{array}$	-	1.2	1.7	dB
		$\begin{split} \Gamma_{\text{s}} &= \Gamma_{\text{opt}}; \text{ I}_{\text{C}} = 5 \text{ mA}; \text{ V}_{\text{CE}} = 6 \text{ V}; \\ \text{f} &= 900 \text{ MHz}; \text{ T}_{\text{amb}} = 25 ^{\circ}\text{C} \end{split}$	-	1.6	2.1	dB
		$\Gamma_{s} = \Gamma_{opt}$; I _C = 1.25 mA; V _{CE} = 6 V; f = 2 GHz; T _{amb} = 25 °C	-	1.9	-	dB
P _{L1}	output power at 1 dB gain compression	$I_{C} = 5 \text{ mA}; V_{CE} = 6 \text{ V}; R_{L} = 50 \Omega;$ f = 900 MHz; T _{amb} = 25 °C	_	4	-	dBm
ITO	third-order intercept point	note 2	-	10	-	dBm

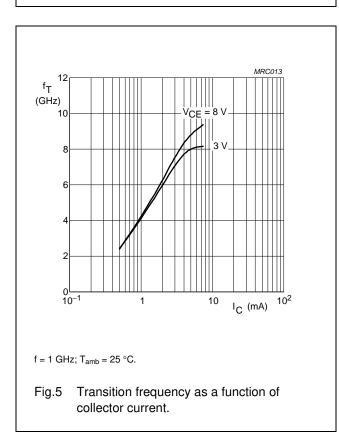
Notes

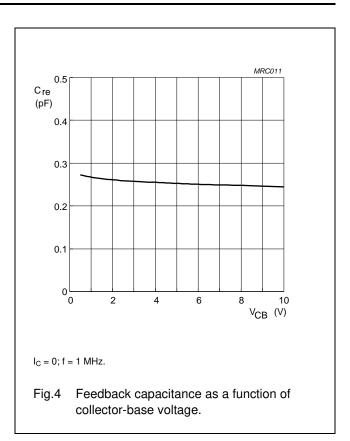
1. G_{UM} is the maximum unilateral power gain, assuming S_{12} is zero and

$$G_{UM} = 10 \log \frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)} dB$$

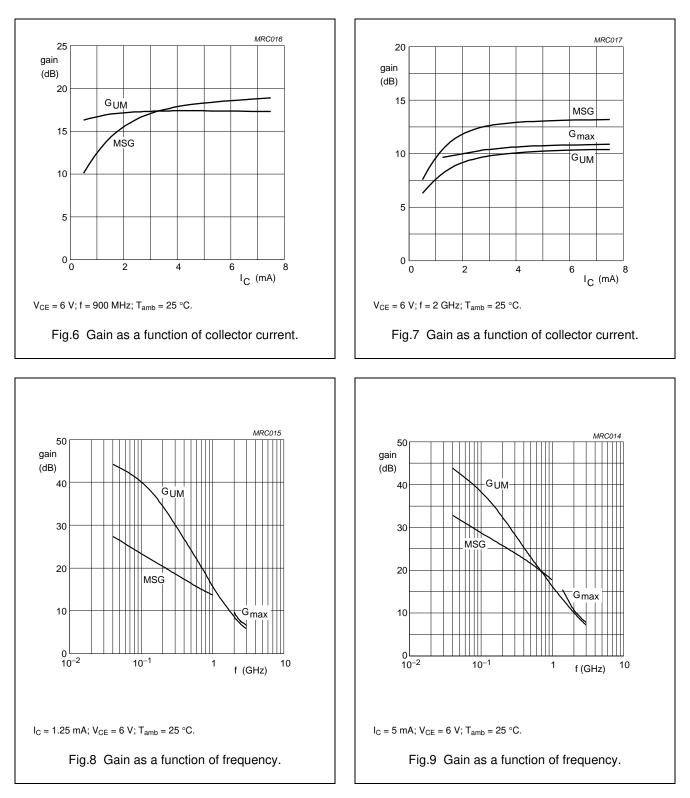
2. $I_C = 5 \text{ mA}; V_{CE} = 6 \text{ V}; R_L = 50 \Omega; f = 900 \text{ MHz}; T_{amb} = 25 \text{ °C}; f_p = 900 \text{ MHz}; f_q = 902 \text{ MHz}; \text{ measured at } f_{(2p-q)} = 898 \text{ MHz and at } f_{(2q-p)} = 904 \text{ MHz}.$

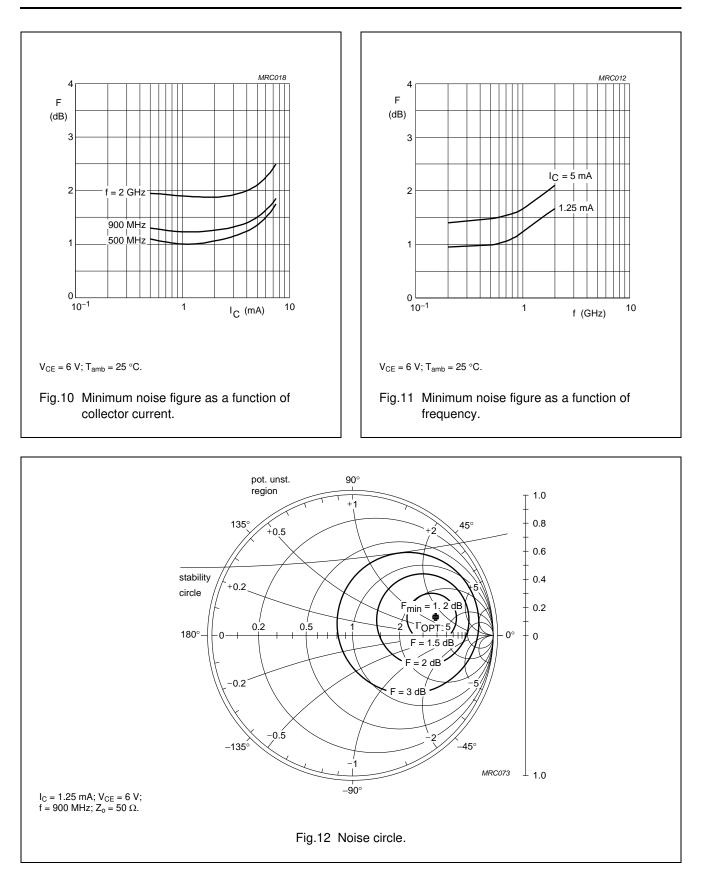


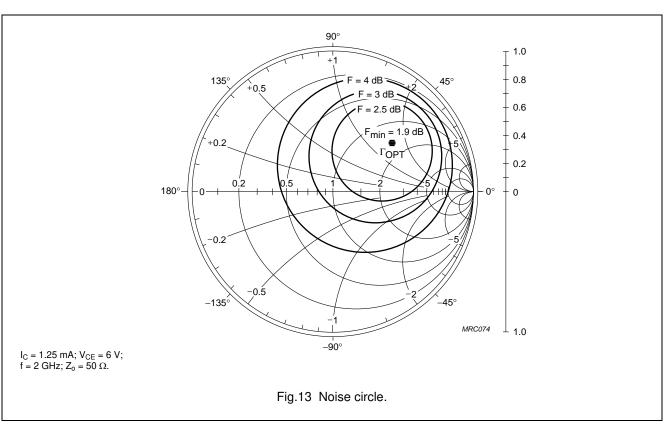


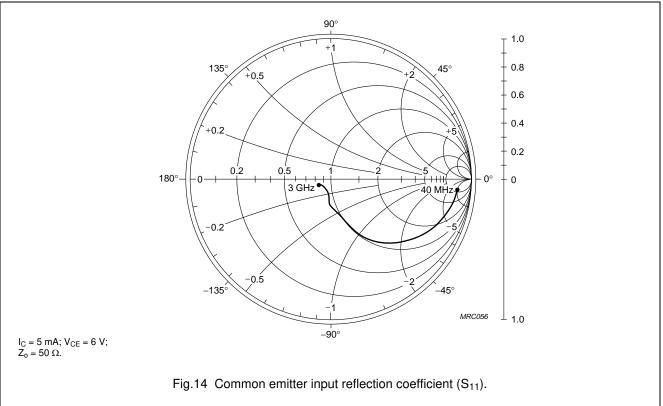


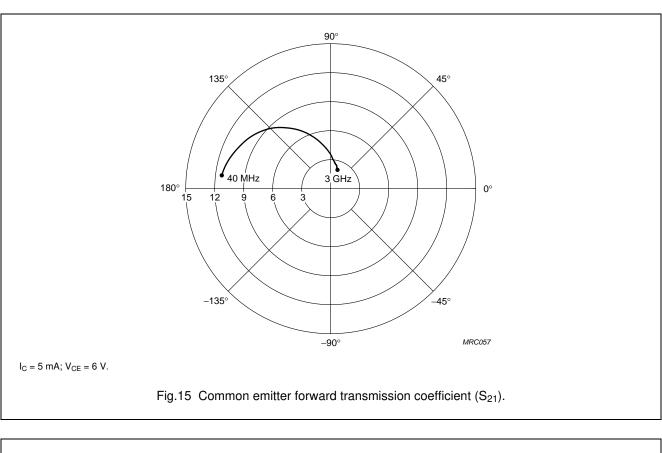
In Figs 6 to 9, G_{UM} = maximum unilateral power gain; MSG = maximum stable gain; G_{max} = maximum available gain.

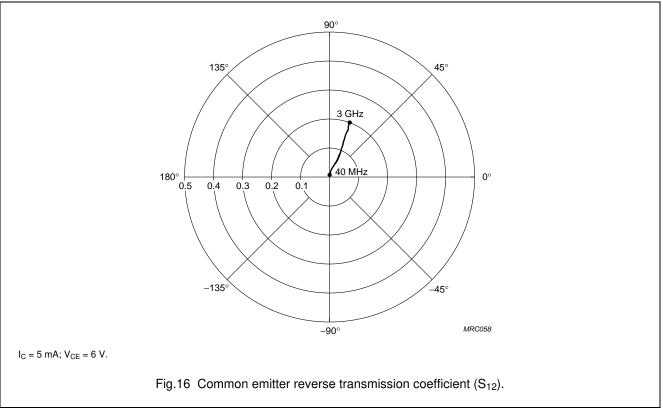


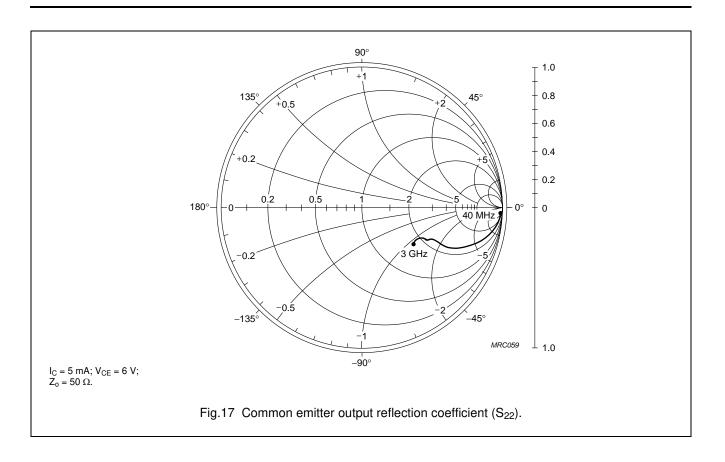








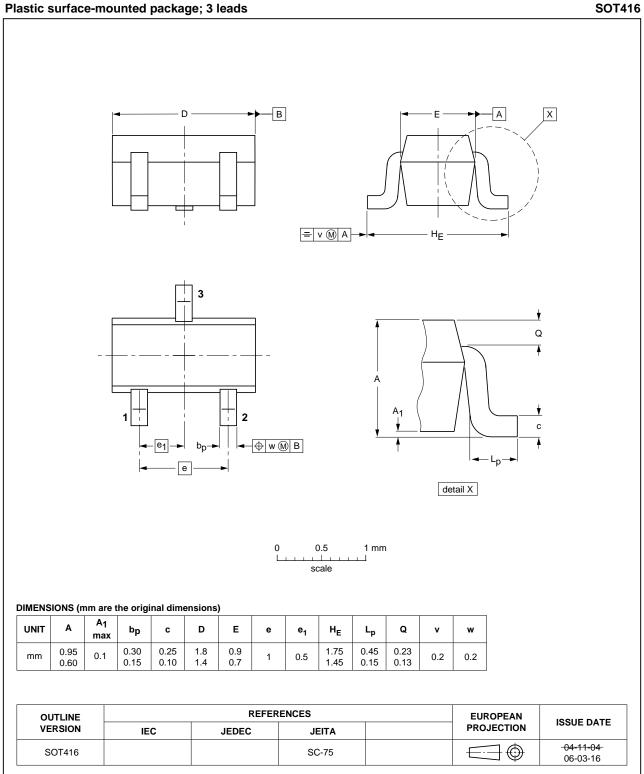




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NPN 9 GHz wideband transistor

PACKAGE OUTLINE



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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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